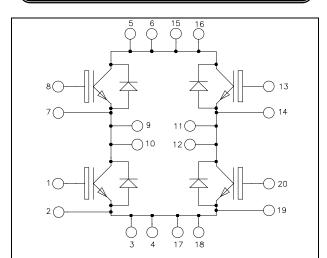
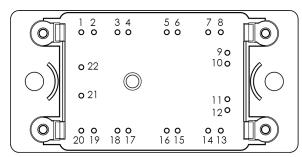
Full - Bridge High speed Trench + Field Stop IGBT4 Power Module





Pins 5/6/15/16 ; 3/4/17/18 ; 9/10 ; 11/12 must be shorted together

## $V_{CES} = 1200V$ $I_{C} = 25A$ @ Tc = 80°C

#### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- High speed Trench + Field Stop IGBT 4 Technology
  - Low voltage drop
  - Low leakage current
  - Low switching losses
- Very low stray inductance
- Internal thermistor for temperature monitoring

#### **Benefits**

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- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

### All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

### Absolute maximum ratings (per IGBT)

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Voltage		1200	V
Ţ	Continuous Collector Current $T_C =$	25°C	50	A
$I_{C}$	Continuous Conector Current $T_{\rm C} = 80$	80°C	25	Α
$I_{CM}$	Pulsed Collector Current $T_C =$	25°C	100	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{D}$	Power Dissipation		165	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



Electrical	Characteristics	(per IGBT)
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Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				50	μА
V <sub>CE(sat)</sub>	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.78	1.78 2.05	2.42	V
	Collector Emitter Saturation Voltage	$I_C = 25A$	$T_j = 150$ °C		2.6		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 0.85 \text{ mA}$		5.3	5.8	6.3	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V$ , $V_{CE} = 0V$				150	nA

### **Dynamic Characteristics** (per IGBT)

•	Characteristic	Test Condition	ns	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			1430		
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 25V$			95		pF
$C_{res}$	Reverse Transfer Capacitance	f = 1MHz			75		
$Q_{G}$	Gate charge	$V_{GE} = 15V, I_{C}$ $V_{CE} = 960V$	= 25A		115		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Swit	tching (25°C)		27		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			41		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 25A$			277		
$T_{\mathrm{f}}$	Fall Time	$R_G = 19\Omega$			17		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C)			26		
$T_{r}$	Rise Time	$V_{GE} = \pm 15V$			35		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_C = 25A$			347		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 19\Omega$			50		ı
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 150$ °C		2.4		mJ
$\mathrm{E}_{\mathrm{off}}$	Turn off Energy	$I_C = 25A$ $R_G = 19\Omega$	$T_j = 150$ °C		1.4		111,)
$I_{sc}$	Short Circuit data	$V_{GE} \le 15V ; V_1$ $t_p \le 10 \mu s ; T_1 =$			90		A
$R_{thJC}$	Junction to Case Thermal Resistance	·				0.9	°C/W

## Diode ratings and characteristics (per diode)

Symbol	Characteristic Test Conditions		Min	Typ	Max	Unit	
$V_{RRM}$	Peak Repetitive Reverse Voltage				1200	V	
$I_{RM}$	Reverse Leakage Current	V <sub>R</sub> =1200V				100	μΑ
$I_{F}$	DC Forward Current	$Tc = 80^{\circ}C$			25		A
		$I_F = 25A$			2.6	3.3	
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 50A$			3.2		V
		$I_F = 25A$	$T_{j} = 125^{\circ}C$		1.8		ı
+	, D. D. Ti	$T_j = 25$ °C		320		nc	
t <sub>rr</sub>	Reverse Recovery Time	$I_{\rm F} = 25A$	$T_{j} = 125^{\circ}C$		360		ns
0	Payaraa Pagayary Charga	$V_R = 667V$ $di/dt = 200A/\mu s$	$T_j = 25$ °C		480		nC
Q <sub>rr</sub>	Reverse Recovery Charge	,	$T_{j} = 125^{\circ}C$		1800		IIC
$R_{thJC}$	Junction to Case Thermal Resistance					1.4	°C/W



### **Temperature sensor NTC**

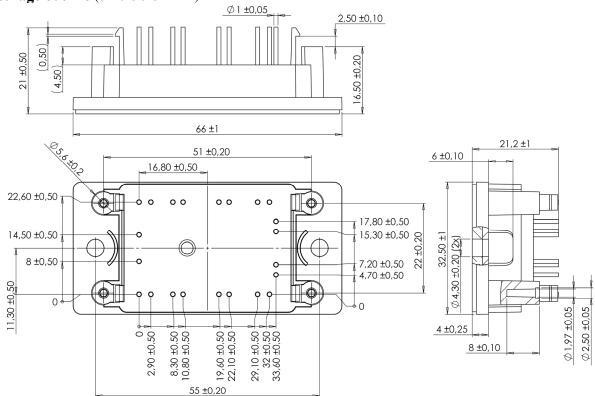
S	ymbol	Characteristic	Min	Тур	Max	Unit
	R <sub>25</sub>	Resistance @ 25°C		22		kΩ
Δ	$R_{25}/R_{25}$	Resistance tolerance			5	%
	ΔΒ/Β	Beta tolerance			3	70
	B <sub>25/100</sub>	$T_{25} = 298.16 \text{ K}$		3980		K

$$R_T = \frac{R_{25}}{\exp \left[ B_{25/100} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \begin{array}{l} \text{T: Thermistor temperature} \\ \text{R}_{\text{T:}} \text{ Thermistor value at T} \end{array} \right.$$

### Thermal and package characteristics

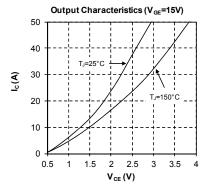
Symbol	Characteristic			Min	Typ	Max	Unit
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range			-40		150	
$T_{STG}$	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		125	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					75	g

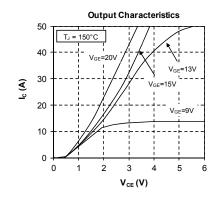
### package outline (dimensions in mm)

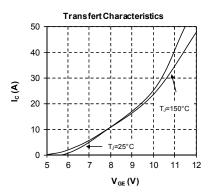


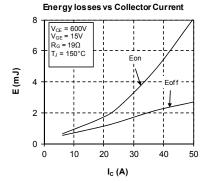


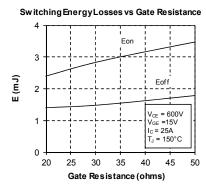
### **Typical Performance Curve**

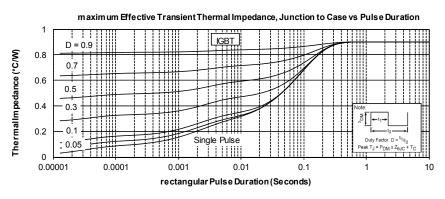




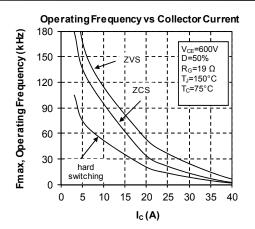


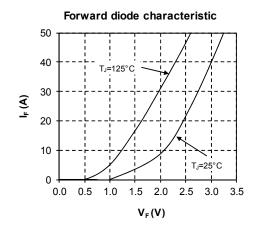


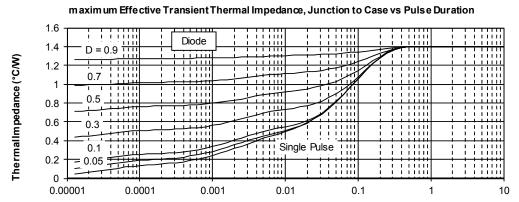














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